MOS FET Relays

G3VM-601BY/EY

Analog-switching MOS FET Relay with a Dielectric Strength of 5 kVAC between I/O Using Optical Isolation

- Switches minute analog signals.
- Switching AC and DC.
- Peak load voltage of 600 V.
- Dielectric strength of 5 kVAC between I/O.

■ Application Examples

- Electronic automatic exchange systems
- FA systems
- · Measurement devices
- · Security systems

■List of Models



Note: The actual product is marked differently from the image shown here.

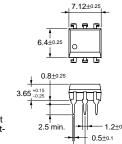
Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	600 VAC	G3VM-601BY	50	
	Surface-mounting		G3VM-601EY		
	terminals		G3VM-601EY(TR)		1,500

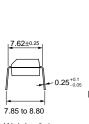
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



Note: The actual product is marked differently from the image

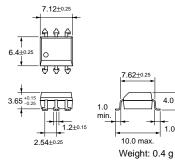




Note: The actual product Weight: 0.4 g

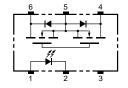




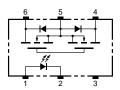


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-601BY



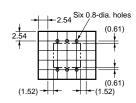
G3VM-601EY



1.0 min.

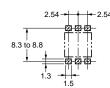
■ PCB Dimensions (Bottom View)

G3VM-601BY



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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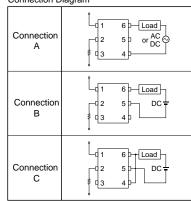


■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current		I _F	50	mA		
	Repetitive peak LED forward current		I _{FP}	1	Α	100 μs pulses, 100 pps	
	LED forward current reduction rate		Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage		V_R	5	V		
	Connection temperature		Tj	125	°C		
Output	Output dielectric strength		V _{OFF}	600	V		
	Continuous load current	Connection A	I _O	100	mA		
		Connection B		100			
		Connection C		200			
	ON current reduction rate	Connection A	Δ I _{ON} /°C	-1.0	mA/°C	Ta ≥ 25°C	
		Connection B		-1.0			
		Connection C		-2.0			
	Connection temperature		Tj	125	°C		
Dielectric strength between input and output (See note 1.)		V _{I-O}	5,000	Vrms	AC for 1 min		
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation		
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation		
Soldering temperature (10 s)			260	°C	10 s		

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

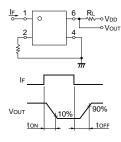
Connection Diagram



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage		V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current		I _R			10	μА	V _R = 5 V	
	Capacity between terminals		C _T		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current		I _{FT}		1.6	5	mA	I _O = 100 mA	
Output	Maximum resistance with output ON	Connection A	R _{ON}		25	35	Ω	I _F = 10 mA, I _O = 100 mA	
					30	45	Ω	I _F = 10 mA, I _O = 100 mA	
		Connection B			23	35	Ω	I _F = 10 mA, I _O = 100 mA	
		Connection C			12	18	Ω	I _F = 10 mA, I _O = 200 mA	
	Current leakage when the relay is open		I _{LEAK}			1.0	μА	V _{OFF} = 600 V	
Capacity between I/O terminals			C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance			R _{I-O}	1,000			МΩ	V_{I-O} = 500 VDC, RoH \leq 60%	
Turn-ON time			tON		0.2	1.5	ms	I _F = 5 mA, R _L = 200 Ω V _{DD} = 20 V (See note 2	
Turn-OFF time			tOFF		0.2	1.0	ms		

Note: 2. Turn-ON and Turn-OFF Times



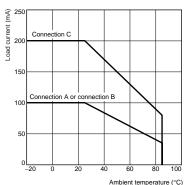
■Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}			480	V
Operating LED forward current	I _F	7.5	15	25	mA
Continuous load current	Io			100	mA
Operating temperature	T _a	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-601BY(EY)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.